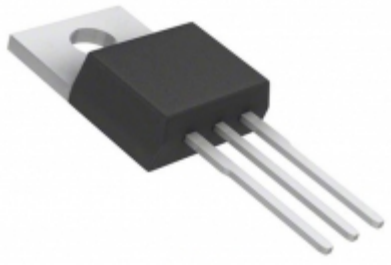


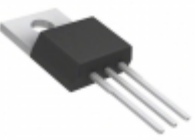
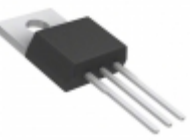




	<h2 style="color: red;">FQP13N06</h2> <p>Hersteller-Teilenummer: FQP13N06</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 13A TO-220</p> <p>Datenblätter: 1.FQP13N06.pdf 2.FQP13N06.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32375 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N06
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 13A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32375 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	45W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	13A (Tc)
Rds On (Max) @ Id, Vgs	135 mOhm @ 6.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	310pF @ 25V
Verpackung	Tube

FQP13N06 ist neu im Original, Suche FQP13N06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N06 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP13N06: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p>FQP13N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>
 <p>FQP12P10 Fairchild/ON Semiconductor MOSFET P-CH 100V 11.5A TO-220</p>	 <p>FQP13N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p>FQP12P20 AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 11.5A TO-220</p>	 <p>FQP13N06L FQP13N06 Original FQP13N06L FQP13N06 Original</p>

heiße Teile

Mehr

FQP10N60CF	FQP10N60C_07	FQP10N65	FQP10N65C	FQP10N80
FQP11N40C	FQP11N40C	FQP11N50CF	FQP11N50CF	FQP11N60
FQP11N60C	FQP11N65C	FQP11P06	FQP11P06	FQP12N20
FQP12N60	FQP12N60	FQP12N60C	FQP12N60C	FQP12N65C
FQP12P10	FQP12P10	FQP12P20	FQP12P20	FQP13N06
FQP13N06L	FQP13N06L	FQP13N10	FQP13N10	FQP13N10L
FQP13N10L	FQP13N50	FQP13N50	FQP13N50C	FQP13N50C
FQP13N60C	FQP140N03	FQP140N03L	FQP14N15	FQP14N15
FQP14N30	FQP14N30	FQP14N80	FQP14N80C	FQP15N16
FQP15N30	FQP15N50	FQP15N60	FQP15N65	FQP15N80

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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